

# **Transient Voltage Suppression Diode**

#### **General Description**

GOLDEN GATE INTEGRATED CIRCUITS

The GG0501SG is a transient voltage suppressing diode to protect one power line, or one control line, or one low speed data line from overvoltage hazard of Electrostatic Discharge (ESD), Electrical Fast Transients (EFT) and Lightning. The GG0501SG's typical applications are mobile phone Protection, MP3 and digital cameras Protection, Control Signal Lines Protection etc.



#### **Features**

- Provides ESD protection to IEC61000-4-2 level 4
  - ±20kV air discharge
  - ±15kV contact discharge
- Ultra-small body with SOD-523 package
- Fast response speed <1 ns
- Low clamping voltage
- Low operating voltage

#### **Applications**

- Mobile phone Protection
- MP3 Protection
- Digital cameras Protection
- Control Signal Lines Protection
- Power line Protection

# **Pin Configuration**



### **Ordering Information**

Part No	Package	Marking	Material	Packing
GG0501SGTR	SOD-523	51	Halogen free	Tape&Reel



#### **Absolute Maximum Ratings**

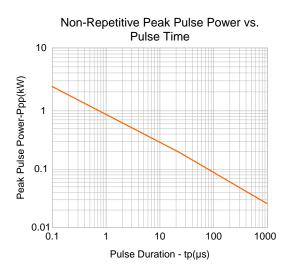
Characteristics	Symbol	Rating	Unit	
Peak Pulse Power (t <sub>P</sub> =8/20µs)	P <sub>Pk</sub>	200	W	
Peak Pulse Current (t <sub>P</sub> =8/20µs)	I <sub>PP</sub>	16	А	
ESD per IEC61000-4-2(Air)		±20	1-27	
ESD per IEC61000-4-2(Contact)	V <sub>ESD-1</sub>	±15	kV	
Lead Soldering Temperature	T <sub>SOL</sub>	260(10sec.)	°C	
Operating Temperature Range	T <sub>OP</sub>	-55 ~ +125	°C	
Storage Temperature Range	T <sub>STO</sub>	-55 ~ +150	۵°C	

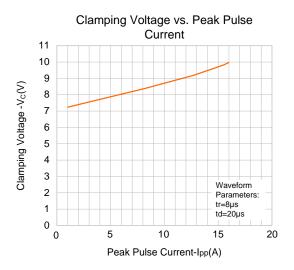
# **Electrical Characteristics (Tamb=25°C)**

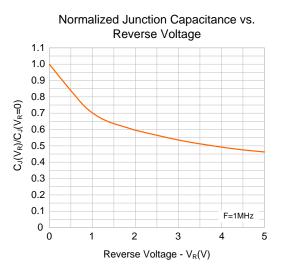
Characteristics	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Stand-Off Voltage	V <sub>RWM</sub>	T=25°C			5	V
Reverse Leakage Current	L <sub>Leak</sub>	V <sub>RWM</sub> =5V,T=25°C			5	μA
Reverse Breakdown Voltage	V <sub>BV</sub>	I <sub>BV</sub> =1mA,T=25°C	6.0		9.0	V
Clamping Voltage	V <sub>CL</sub>	I <sub>PP</sub> =5A, t <sub>P</sub> =8/20µs, T=25°C			9.8	V
Clamping Voltage	V <sub>CL</sub>	I <sub>PP</sub> =16A, t <sub>P</sub> =8/20μs, T=25°C			12.5	V
Channel Input Capacitance	C <sub>N</sub>	V <sub>R</sub> =0V, f=1MHz, T=25°C			160	pF

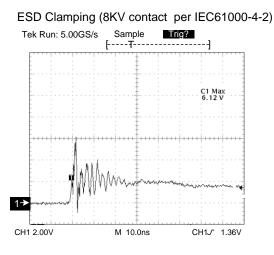


# **Typical Electrical Characteristics Curve**



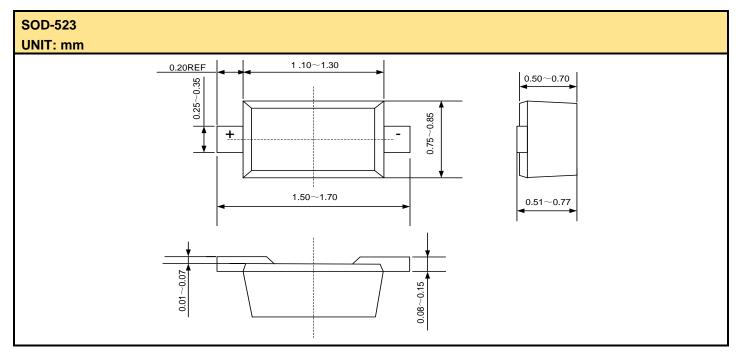








## **Package Outline**



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